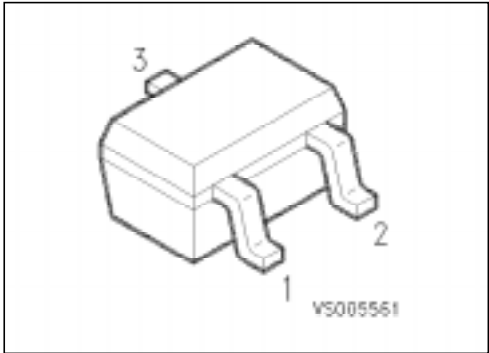


## PNP Silicon AF Transistors

## BC 856W ... BC 860W

### Features

- For AF input stages and driver applications
- High current gain
- Low collector-emitter saturation voltage
- Low noise between 30 Hz and 15 kHz
- Complementary types: BC 847W, BC 848W,  
BC 849W, BC 850W (NPN)



| Type      | Marking | Ordering Code<br>(tape and reel) | Pin Configuration |   |   | Package <sup>1)</sup> |
|-----------|---------|----------------------------------|-------------------|---|---|-----------------------|
|           |         |                                  | 1                 | 2 | 3 |                       |
| BC 856 AW | 3As     | Q62702-C2335                     | B                 | E | C | SOT-323               |
| BC 856 BW | 3Bs     | Q62702-C2292                     |                   |   |   |                       |
| BC 857 AW | 3Es     | Q62702-C2293                     |                   |   |   |                       |
| BC 857 BW | 3Fs     | Q62702-C2294                     |                   |   |   |                       |
| BC 857 CW | 3Gs     | Q62702-C2295                     |                   |   |   |                       |
| BC 858 AW | 3Js     | Q62702-C2296                     |                   |   |   |                       |
| BC 858 BW | 3Ks     | Q62702-C2297                     |                   |   |   |                       |
| BC 858 CW | 3Ls     | Q62702-C2298                     |                   |   |   |                       |
| BC 859 AW | 4As     | Q62702-C2299                     |                   |   |   |                       |
| BC 859 BW | 4Bs     | Q62702-C2300                     |                   |   |   |                       |
| BC 859 CW | 4Cs     | Q62702-C2301                     |                   |   |   |                       |
| BC 860 BW | 4Fs     | Q62702-C2302                     |                   |   |   |                       |
| BC 860 CW | 4Gs     | Q62702-C2303                     |                   |   |   |                       |

<sup>1)</sup>For detailed information see chapter Package Outlines.

### Maximum Ratings

| Description                                    | Symbol    | BC 856W    | BC 857W<br>BC 860W | BC 858W<br>BC 859W | Unit |
|------------------------------------------------|-----------|------------|--------------------|--------------------|------|
| Collector-emitter voltage                      | $V_{CEO}$ | 65         | 45                 | 30                 | V    |
| Collector-base voltage                         | $V_{CBO}$ | 80         | 50                 | 30                 | V    |
| Collector-emitter voltage                      | $V_{CES}$ | 80         | 50                 | 30                 | V    |
| Emitter-base voltage                           | $V_{EBO}$ | 5          | 5                  | 5                  | V    |
| Collector current                              | $I_C$     | 100        |                    |                    | mA   |
| Collector peak current                         | $I_{CM}$  | 200        |                    |                    | mA   |
| Total power dissipation, $T_s = 115\text{ °C}$ | $P_{tot}$ | 250        |                    |                    | mW   |
| Junction temperature                           | $T_j$     | 150        |                    |                    | °C   |
| Storage temperature range                      | $T_{stg}$ | -65 to 150 |                    |                    | °C   |

### Thermal Resistance

|                                  |             |       |     |
|----------------------------------|-------------|-------|-----|
| Junction - ambient <sup>1)</sup> | $R_{th JA}$ | ≤ 240 | K/W |
| Junction - soldering point       | $R_{th JS}$ | ≤ 105 | K/W |

## Electrical Characteristics

at  $T_A = 25^\circ\text{C}$ , unless otherwise specified.

| Parameter | Symbol | Values |      |      | Unit |
|-----------|--------|--------|------|------|------|
|           |        | min.   | typ. | max. |      |

## DC characteristics

|                                                                                                                                                                                                                                                                                           |               |                                  |                                        |                                  |                     |
|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|---------------|----------------------------------|----------------------------------------|----------------------------------|---------------------|
| Collector-emitter breakdown voltage<br>$I_C = 10\text{ mA}$<br>BC 856W<br>BC 857W, BC 860W<br>BC 858W, BC 859W                                                                                                                                                                            | $V_{(BR)CE0}$ | 65<br>45<br>30                   | —<br>—<br>—                            | —<br>—<br>—                      | V                   |
| Collector-base breakdown voltage<br>$I_C = 10\text{ }\mu\text{A}$<br>BC 856W<br>BC 857W, BC 860W<br>BC 858W, BC 859W                                                                                                                                                                      | $V_{(BR)CB0}$ | 80<br>50<br>30                   | —<br>—<br>—                            | —<br>—<br>—                      |                     |
| Collector-emitter breakdown voltage<br>$I_C = 10\text{ }\mu\text{A}$ , $V_{BE} = 0$<br>BC 856W<br>BC 857W, BC 860W<br>BC 858W, BC 859W                                                                                                                                                    | $V_{(BR)CES}$ | 80<br>50<br>30                   | —<br>—<br>—                            | —<br>—<br>—                      |                     |
| Emitter-base breakdown voltage<br>$I_E = 1\text{ }\mu\text{A}$                                                                                                                                                                                                                            | $V_{(BR)EB0}$ | 5                                | —                                      | —                                |                     |
| Collector cutoff current<br>$V_{CB} = 30\text{ V}$<br>$V_{CB} = 30\text{ V}$ , $T_A = 150^\circ\text{C}$                                                                                                                                                                                  | $I_{CB0}$     | —<br>—                           | —<br>—                                 | 15<br>5                          | nA<br>$\mu\text{A}$ |
| DC current gain<br>$I_C = 10\text{ }\mu\text{A}$ , $V_{CE} = 5\text{ V}$<br>BC 856 AW ... BC 859 AW<br>BC 856 BW ... BC 860 BW<br>BC 857 CW ... BC 860 CW<br>$I_C = 2\text{ mA}$ , $V_{CE} = 5\text{ V}$<br>BC 856 AW ... BC 859 AW<br>BC 856 BW ... BC 860 BW<br>BC 857 CW ... BC 860 CW | $h_{FE}$      | —<br>—<br>—<br>125<br>220<br>420 | 140<br>250<br>480<br>180<br>290<br>520 | —<br>—<br>—<br>250<br>475<br>800 | —                   |
| Collector-emitter saturation voltage <sup>1)</sup><br>$I_C = 10\text{ mA}$ , $I_B = 0.5\text{ mA}$<br>$I_C = 100\text{ mA}$ , $I_B = 5\text{ mA}$                                                                                                                                         | $V_{CEsat}$   | —<br>—                           | 75<br>250                              | 300<br>650                       | mV                  |
| Base-emitter saturation voltage <sup>1)</sup><br>$I_C = 10\text{ mA}$ , $I_B = 0.5\text{ mA}$<br>$I_C = 100\text{ mA}$ , $I_B = 5\text{ mA}$                                                                                                                                              | $V_{BEsat}$   | —<br>—                           | 700<br>850                             | —<br>—                           |                     |
| Base-emitter voltage<br>$I_C = 2\text{ mA}$ , $V_{CE} = 5\text{ V}$<br>$I_C = 10\text{ mA}$ , $V_{CE} = 5\text{ V}$                                                                                                                                                                       | $V_{BE(on)}$  | 600<br>—                         | 650<br>—                               | 750<br>820                       |                     |

<sup>1)</sup>Pulse test:  $t \leq 300\text{ }\mu\text{s}$ ,  $D = 2\%$ .

**Electrical Characteristics**at  $T_A = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified.

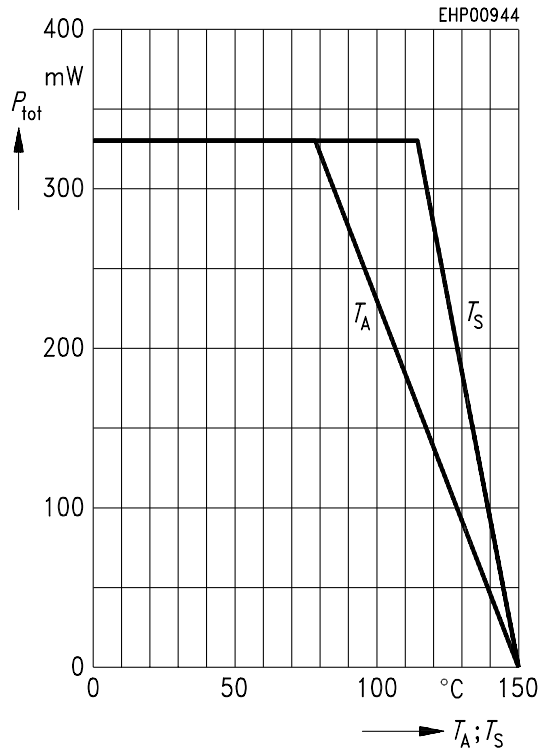
| Parameter | Symbol | Values |      |      | Unit |
|-----------|--------|--------|------|------|------|
|           |        | min.   | typ. | max. |      |

**AC characteristics**

|                                                                                                                                                                                                                             |           |                  |                          |                  |               |
|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-----------|------------------|--------------------------|------------------|---------------|
| Transition frequency<br>$I_C = 20\text{ mA}$ , $V_{CE} = 5\text{ V}$ , $f = 100\text{ MHz}$                                                                                                                                 | $f_T$     | —                | 250                      | —                | MHz           |
| Output capacitance<br>$V_{CB} = 10\text{ V}$ , $f = 1\text{ MHz}$                                                                                                                                                           | $C_{obo}$ | —                | 3                        | —                | pF            |
| Input capacitance<br>$V_{CB} = 0.5\text{ V}$ , $f = 1\text{ MHz}$                                                                                                                                                           | $C_{ibo}$ | —                | 10                       | —                |               |
| Short-circuit input impedance<br>$I_C = 2\text{ mA}$ , $V_{CE} = 5\text{ V}$ , $f = 1\text{ kHz}$<br>BC 856 AW ... BC 859 AW<br>BC 856 BW ... BC 860 BW<br>BC 857 CW ... BC 860 CW                                          | $h_{11e}$ | —<br>—<br>—      | 2.7<br>4.5<br>8.7        | —<br>—<br>—      | k $\Omega$    |
| Open-circuit reverse voltage transfer ratio<br>$I_C = 2\text{ mA}$ , $V_{CE} = 5\text{ V}$ , $f = 1\text{ kHz}$<br>BC 856 AW ... BC 859 AW<br>BC 856 BW ... BC 860 BW<br>BC 857 CW ... BC 860 CW                            | $h_{12e}$ | —<br>—<br>—      | 1.5<br>2.0<br>3.0        | —<br>—<br>—      | $10^{-4}$     |
| Short-circuit forward current transfer ratio<br>$I_C = 2\text{ mA}$ , $V_{CE} = 5\text{ V}$ , $f = 1\text{ kHz}$<br>BC 856 AW ... BC 859 AW<br>BC 856 BW ... BC 860 BW<br>BC 857 CW ... BC 860 CW                           | $h_{21e}$ | —<br>—<br>—      | 200<br>330<br>600        | —<br>—<br>—      | —             |
| Open-circuit output admittance<br>$I_C = 2\text{ mA}$ , $V_{CE} = 5\text{ V}$ , $f = 1\text{ kHz}$<br>BC 856 AW ... BC 859 AW<br>BC 856 BW ... BC 860 BW<br>BC 857 CW ... BC 860 CW                                         | $h_{22e}$ | —<br>—<br>—      | 18<br>30<br>60           | —<br>—<br>—      | $\mu\text{S}$ |
| Noise figure<br>$I_C = 0.2\text{ mA}$ , $V_{CE} = 5\text{ V}$ , $R_S = 2\text{ k}\Omega$<br>$f = 30\text{ Hz} \dots 15\text{ kHz}$ BC 859W<br>BC 860W<br>$f = 1\text{ kHz}$ , $\Delta f = 200\text{ Hz}$ BC 859W<br>BC 860W | $F$       | —<br>—<br>—<br>— | 1.2<br>1.0<br>1.0<br>1.0 | 4<br>3<br>4<br>4 | dB            |
| Equivalent noise voltage<br>$I_C = 0.2\text{ mA}$ , $V_{CE} = 5\text{ V}$ , $R_S = 2\text{ k}\Omega$<br>$f = 10\text{ Hz} \dots 50\text{ Hz}$<br>BC 860W                                                                    | $V_n$     | —                | —                        | 0.110            | $\mu\text{V}$ |

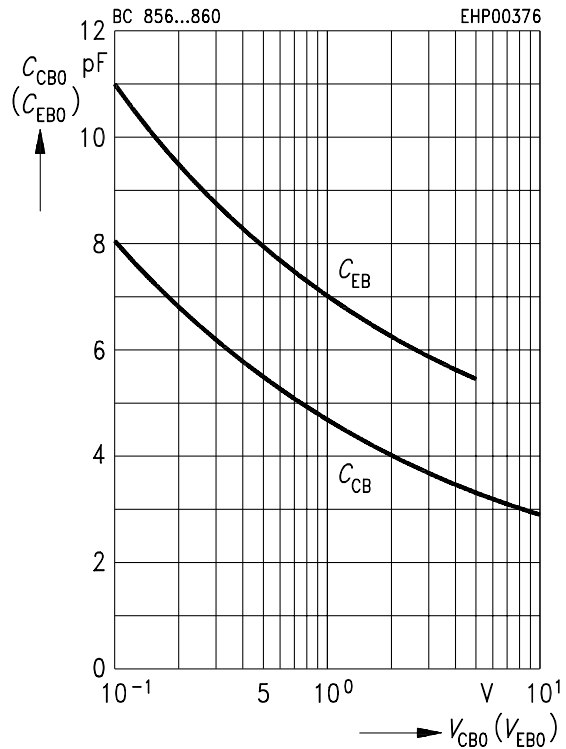
## Total power dissipation $P_{\text{tot}} = f(T_A^*; T_S)$

\* Package mounted on epoxy

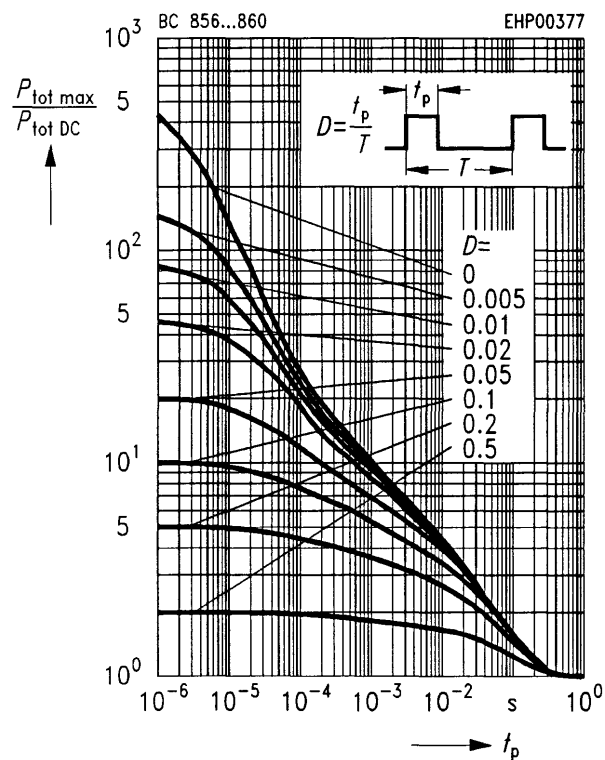


## Collector-base capacitance $C_{CB0} = f(V_{CB0})$

Emitter-base capacitance  $C_{EB0} = f(V_{EB0})$

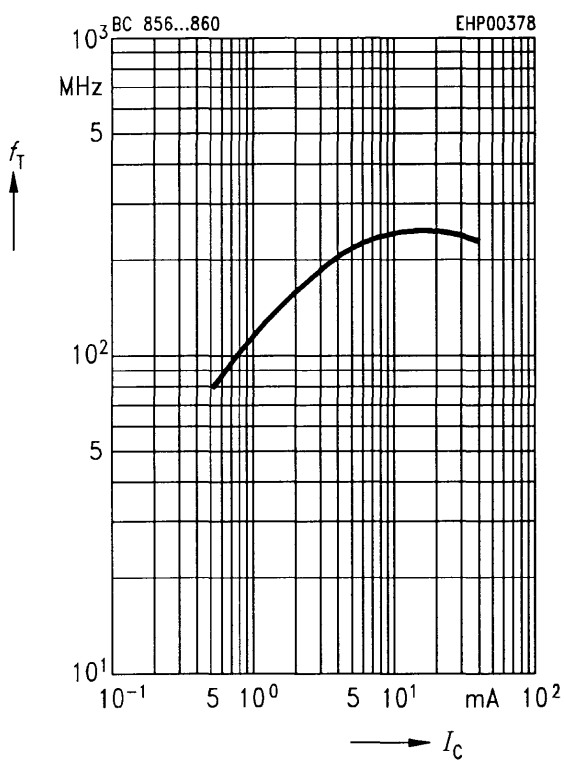


## Permissible pulse load $P_{\text{tot max}}/P_{\text{tot DC}} = f(t_p)$



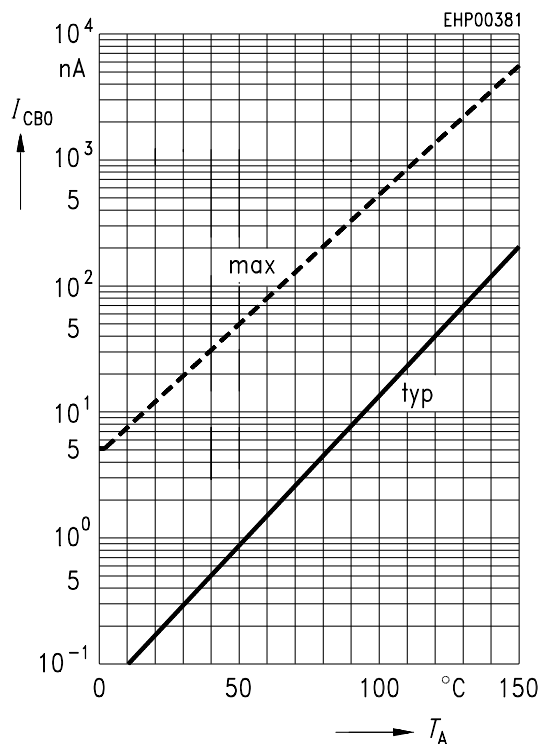
## Transition frequency $f_T = f(I_C)$

$V_{CE} = 5 \text{ V}$



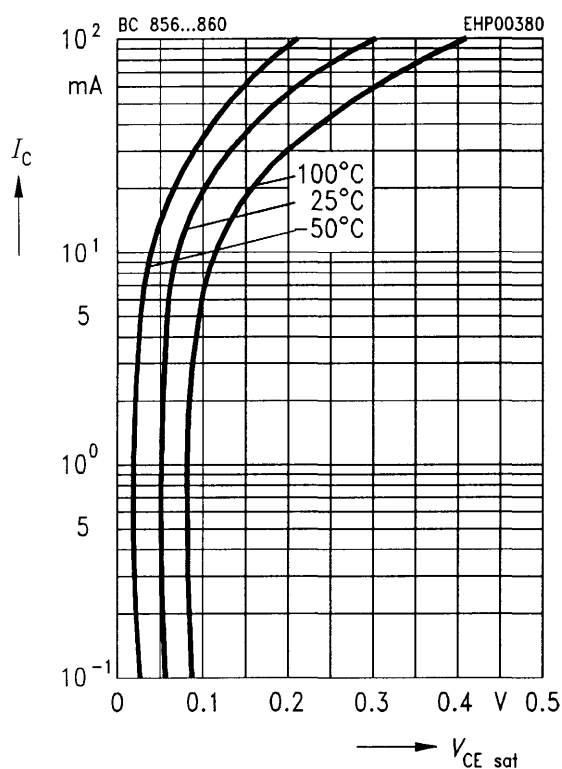
## Collector cutoff current $I_{CB0} = f(T_A)$

$V_{CB} = 30 \text{ V}$



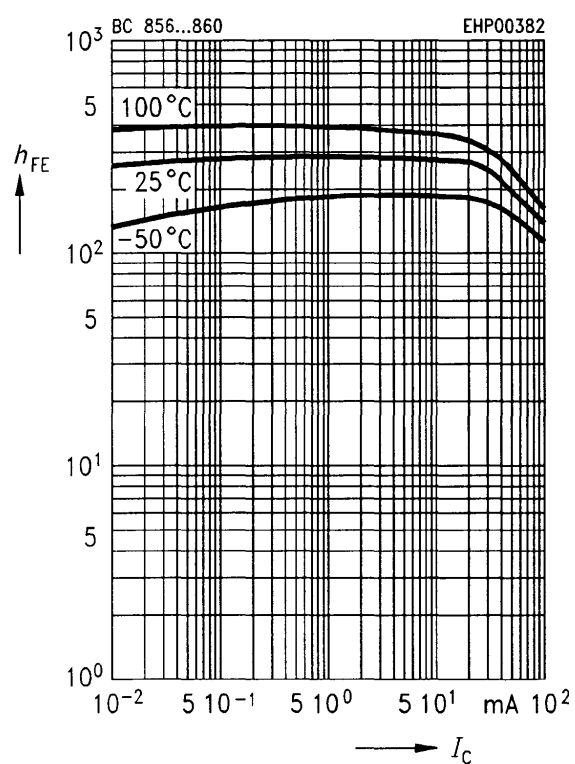
## Collector-emitter saturation voltage

$I_C = f(V_{CEsat}), h_{FE} = 20$



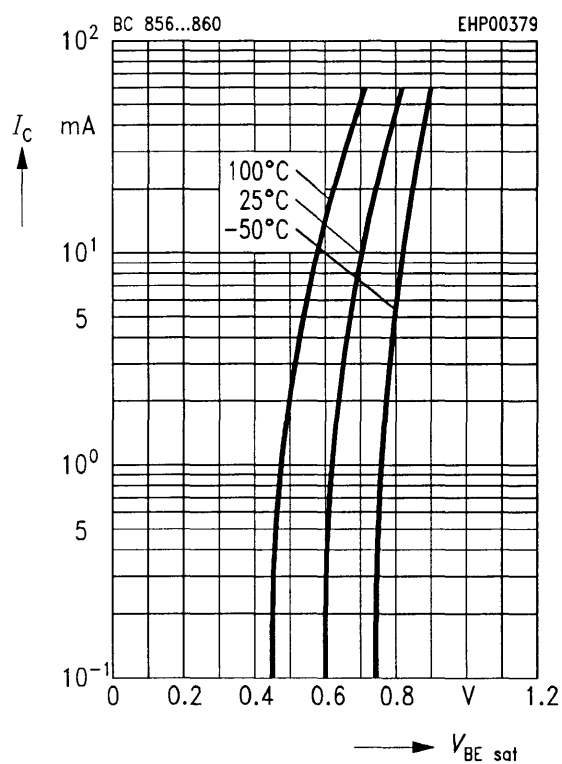
## DC current gain $h_{FE} = f(I_C)$

$V_{CE} = 5 \text{ V}$



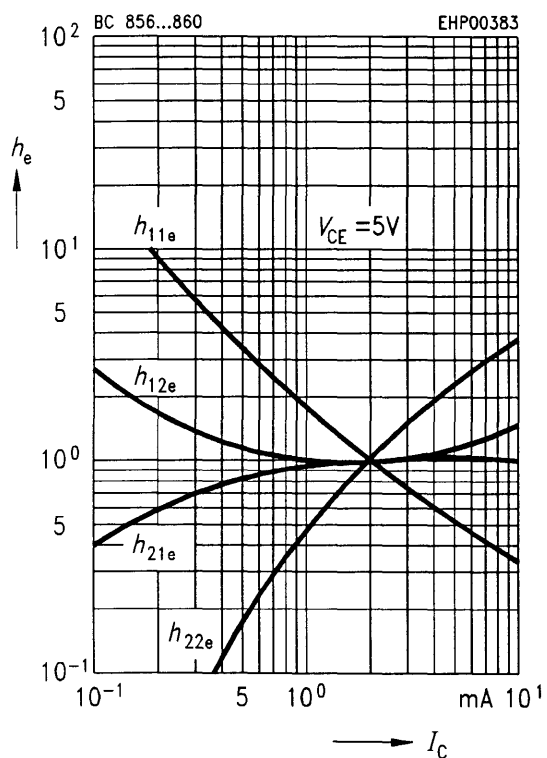
## Base-emitter saturation voltage

$I_C = f(V_{BEsat}), h_{FE} = 20$



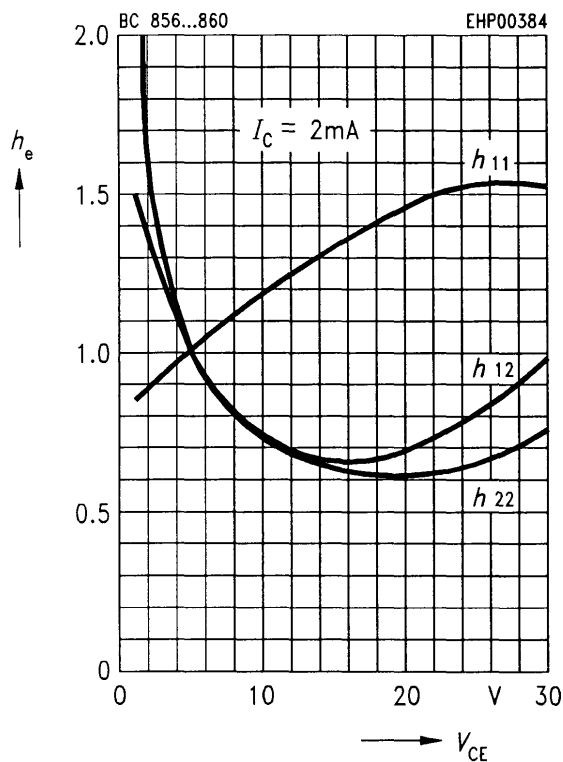
## h parameter $h_e = f(I_C)$ normalized

$V_{CE} = 5 \text{ V}$



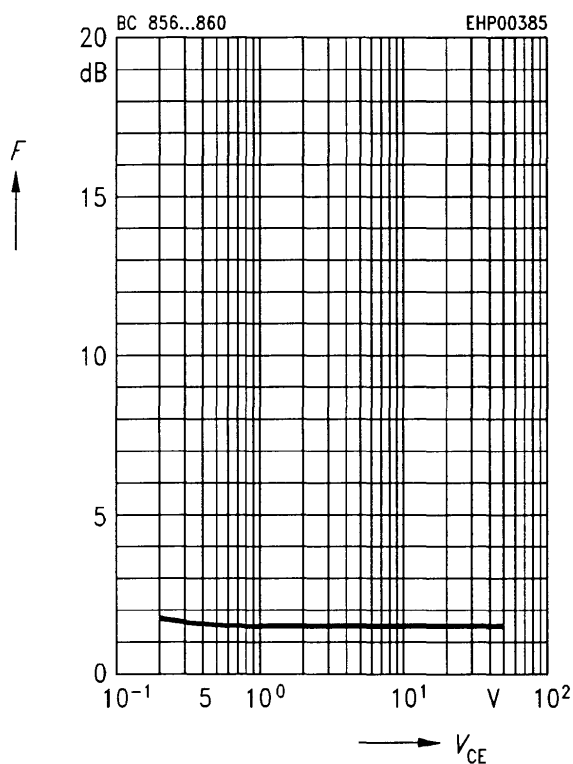
## h parameter $h_e = f(V_{CE})$ normalized

$I_C = 2 \text{ mA}$



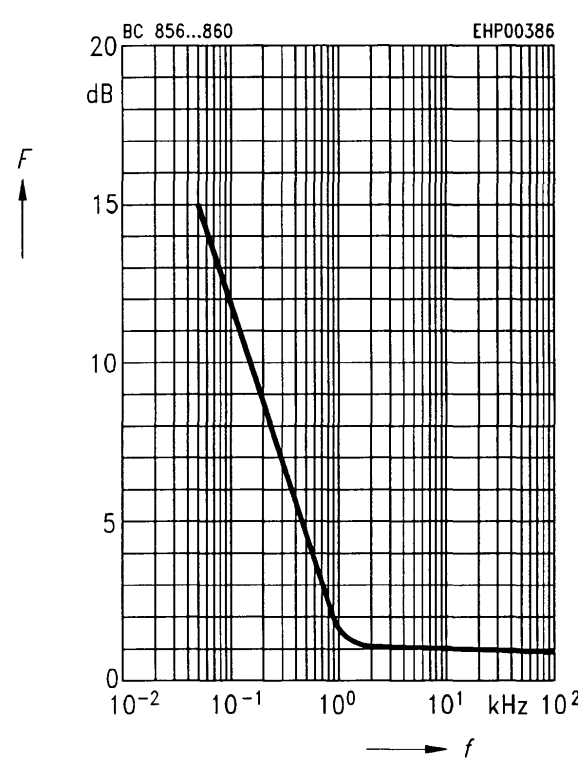
## Noise figure $F = f(V_{CE})$

$I_C = 0.2 \text{ mA}$ ,  $R_S = 2 \text{ k}\Omega$ ,  $f = 1 \text{ kHz}$



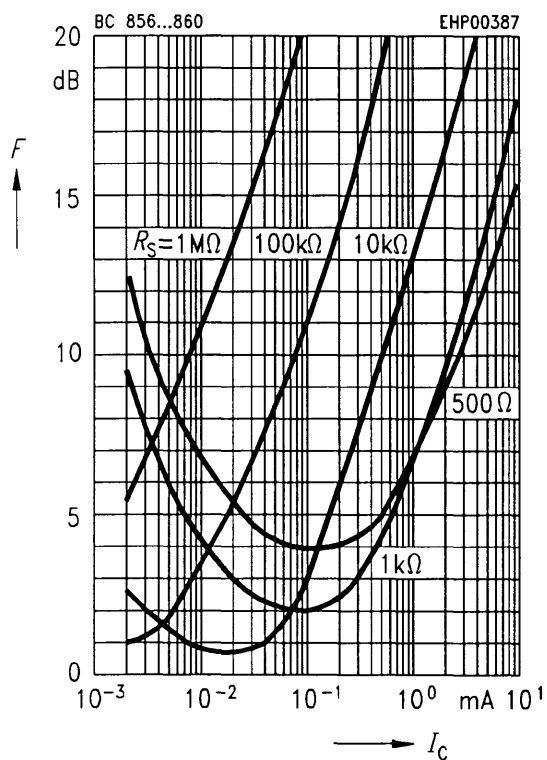
## Noise figure $F = f(f)$

$I_C = 0.2 \text{ mA}$ ,  $V_{CE} = 5 \text{ V}$ ,  $R_S = 2 \text{ k}\Omega$



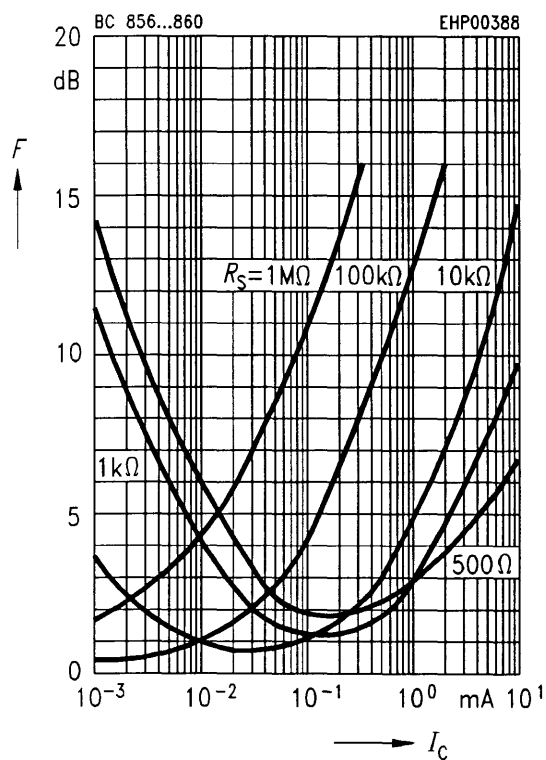
## Noise figure $F = f(I_C)$

$V_{CE} = 5 \text{ V}$ ,  $f = 120 \text{ Hz}$



## Noise figure $F = f(I_C)$

$V_{CE} = 5 \text{ V}$ ,  $f = 1 \text{ kHz}$



## Noise figure $F = f(I_C)$

$V_{CE} = 5 \text{ V}$ ,  $f = 10 \text{ kHz}$

